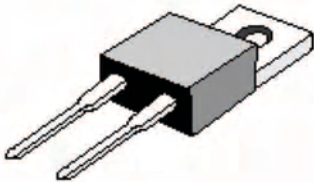


Ultra Fast Rectifiers



Designed for use in switching power supplies, inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

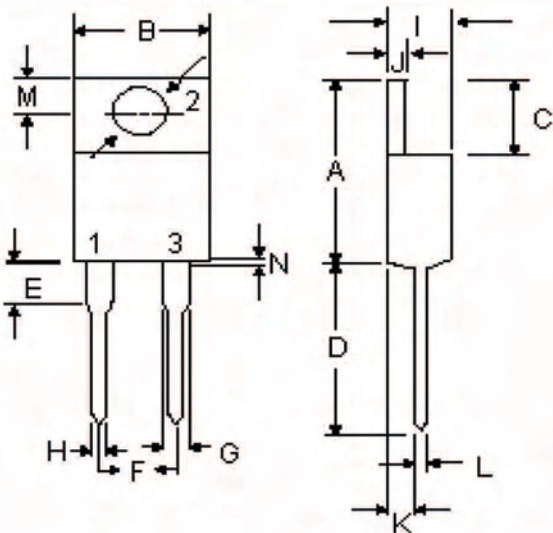
Ultra Fast Recovery Rectifier Diodes



Features:

- High surge capacity.
- Low power loss high efficiency.
- Glass passivated chip junctions.
- 150°C operating junction temperature.
- Low stored charge majority carrier conduction.
- Low forward voltage, high current capability.
- High-switching speed 35 nanosecond recovery time.
- Plastic material used carries Underwriters Laboratory Flammability classification 94V-O.

8 Amperes
20 Volts
TO-220A



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.32
B	9.78	10.42
C	6.01	6.52
D	13.06	14.62
E	3.57	4.07
F	4.83	5.33
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.36
K	2.20	2.97
L	0.33	0.55
M	2.48	2.98
N	—	1.00
O	3.70	3.90

Dimensions : Millimetres

Part Number Table

Description	Part Number
Ultra Fast Rectifiers	MUR820

Maximum Ratings

Characteristic	Symbol	MUR820	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	V
RMS Reverse Voltage	V_R (RMS)	140	
Average Rectifier Forward Current	I_F (AV)	8.0	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I_{FSM}	150	
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	°C

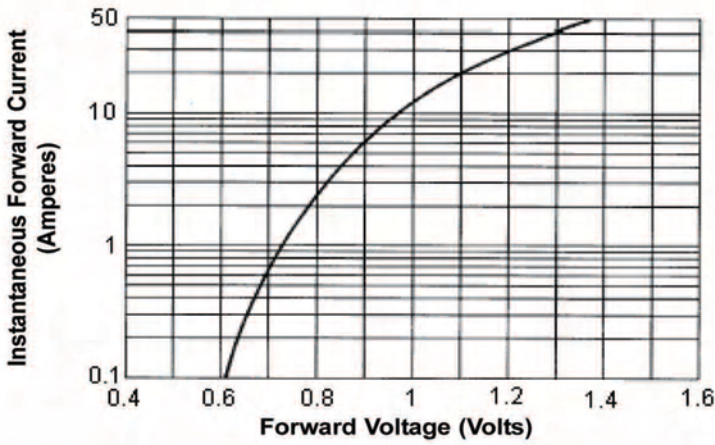
Electrical Characteristics

Characteristic	Symbol	MUR820	Units
Maximum Instantaneous Forward Voltage ($I_F = 8.0$ Amperes $T_C = 25^\circ\text{C}$) ($I_F = 8.0$ Amperes $T_C = 100^\circ\text{C}$)	V_F	0.975 0.880	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^\circ\text{C}$) (Rated DC Voltage, $T_C = 100^\circ\text{C}$)	I_R	10 500	μA
Reverse Recovery Time ($I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{rr} = 0.25\text{A}$)	T_{rr}	35	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts and $f = 1$ MHz)	C_p	120	pF

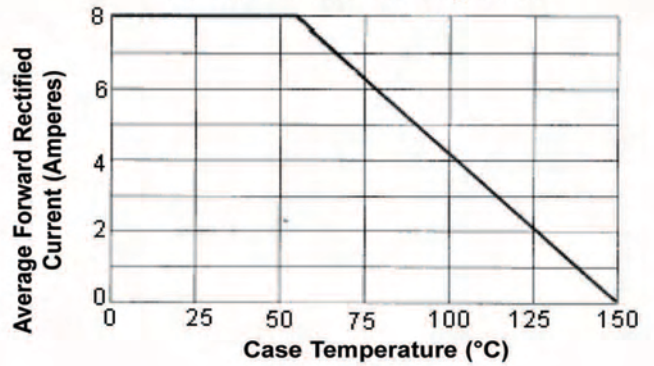
Ultra Fast Rectifiers



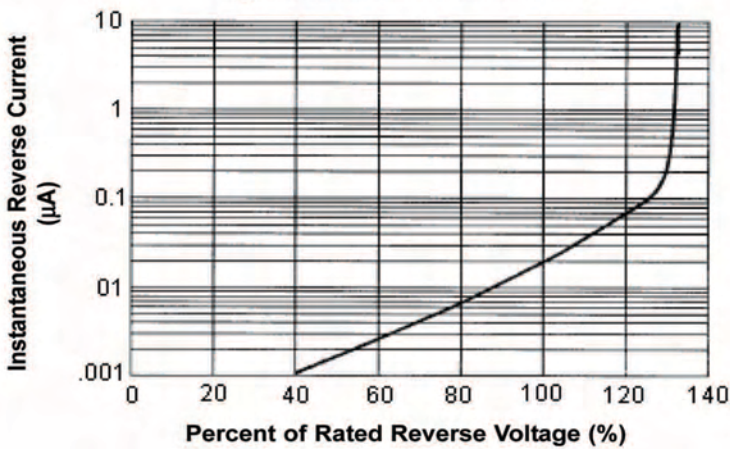
Typical Forward Characteristics



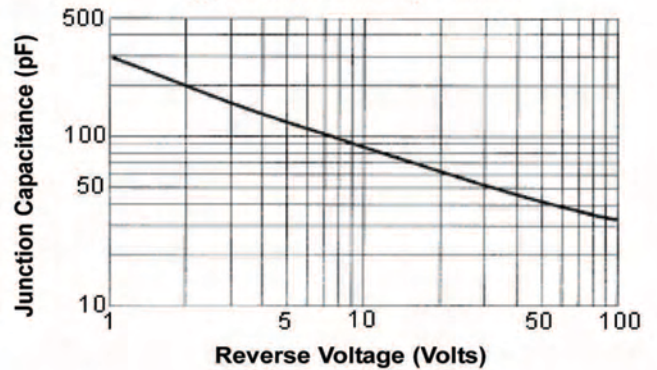
Forward Current Derating Curve



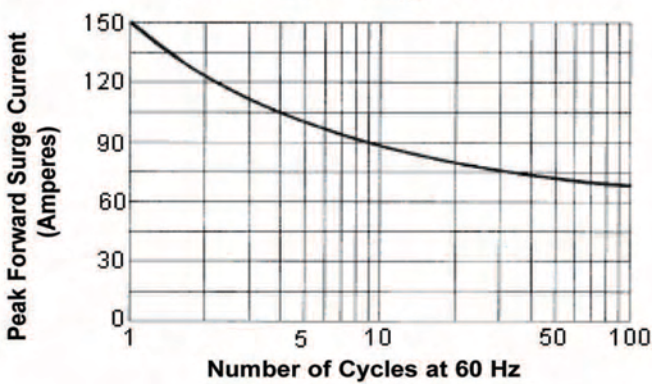
Typical Reverse Characteristics

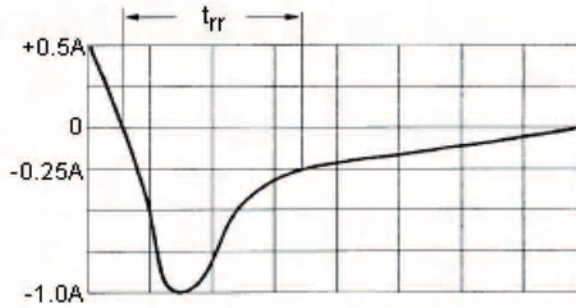
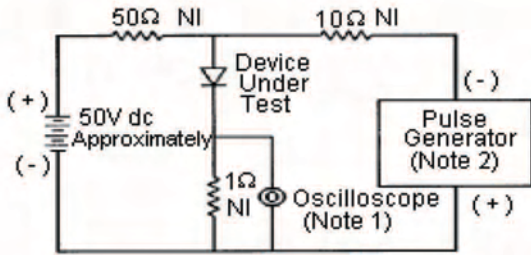


Typical Junction Capacitance



Peak Forward Surge Current





Set time base for 10 ns/div

Reverse Recovery Time Characteristic and Test Circuit Diagram

Notes:

1. Rise Time = 7 ns maximum input impedance = 1M Ω , 22pF.
2. Rise Time = 10 ns maximum input impedance = 50 Ω .

Disclaimer This data sheet and its contents (the "Information") belong to the Premier Farnell Group (the "Group") or are licensed to it. No licence is granted for the use of it other than for information purposes in connection with the products to which it relates. No licence of any intellectual property rights is granted. The Information is subject to change without notice and replaces all data sheets previously supplied. The Information supplied is believed to be accurate but the Group assumes no responsibility for its accuracy or completeness, any error in or omission from it or for any use made of it. Users of this data sheet should check for themselves the Information and the suitability of the products for their purpose and not make any assumptions based on information included or omitted. Liability for loss or damage resulting from any reliance on the Information or use of it (including liability resulting from negligence or where the Group was aware of the possibility of such loss or damage arising) is excluded. This will not operate to limit or restrict the Group's liability for death or personal injury resulting from its negligence. SPC Multicomp is the registered trademark of the Group. © Premier Farnell plc 2010.